FAIRCHILD

SEMICONDUCTOR

FSTU162211 24-Bit Bus Switch with -2V Undershoot Protection and 25 Ω Series Resistors in Outputs (Preliminary)

General Description

The Fairchild Switch FSTU162211 provides 24-bits of highspeed CMOS TTL-compatible bus switching. The low On Resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

The device is organized as a 12-bit or 24-bit bus switch. When \overline{OE}_1 is LOW, the switch is ON and Port 1A is connected to Port 1B. When \overline{OE}_2 is LOW, Port 2A is connected to Port 2B. The A and B Ports are protected against undershoot to support an extended range to 2.0V below ground. Fairchild's integrated Undershoot Hardened Circuit (UHCTM) senses undershoot at the *I*/O and responds by preventing voltage differentials from developing and turning the switch on.

The FSTU162211 has equivalent 25Ω series resistors to reduce signal-reflection noise, eliminating the need for external terminating resistors.

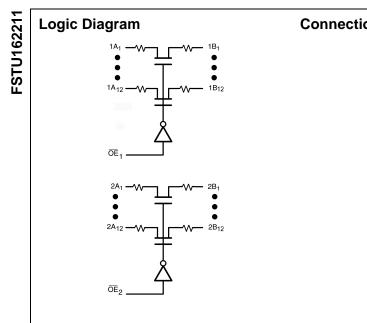
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- Features ■ Undershoot hardened to -2V (A and B Ports)
- Slower output enable times to prevent signal disruption
- \blacksquare 25 Ω switch connection between two ports
- Minimal propagation delay through the switch
- Low Icc
- Zero bounce in flow-through mode
- Control inputs compatible with TTL level
- See Applications Note AN-5008 for details

Ordering Code: Order Number Package Number Package Description FSTU162211MTD MTD56 56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. The ordering code.

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June 2001 Revised June 2001



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1	· · · ·		1					
NC —		56	- OE1					
1A ₁ —	2	55	- OE2					
1A2 -	3	54	— 1B ₁					
1A3 —	4	53	- 1B ₂					
1A4 —	5	52	— 1B ₃					
1A ₅ —	6	51	— 1B4					
1A ₆ —	7	50	— 1B ₅					
GND -	8	49	_ GND					
1A7 —	9	48	— 1B ₆					
1A ₈ —	10	47	— 1B7					
1A9 —	11	46	— 1B ₈					
1A ₁₀ -	12	45	— 1B ₉					
1A ₁₁ —	13	44	- 1B ₁₀					
1A ₁₂ -	14	43	— 1B ₁₁					
2A1-	15	42	— 1B ₁₂					
2A2-	16	41	— 2B1					
V _{CC}	17	40	- 2B ₂					
2A3-	18	39	— 2B3					
GND-	19	38	- GND					
2A4-	20	37	- 2B4					
2A5-	21	36	— 2B5					
2A ₆ —	22	35	— 2B ₆					
2A7-	23	34	— 2B ₇					
2A ₈ —	24	33	— 2B ₈					
2A9-	25	32	— 2B ₉					
2A ₁₀ -	26	31	- 2B ₁₀					
2A ₁₁ -	27	30	— 2B ₁₁					
2A ₁₂ —	28	29	- 2B ₁₂					

Truth Table

Inp	uts	Inputs/Outputs		
OE ₁	OE ₂	1A, 1B 2A, 2		
L	L	1A = 1B	2A = 2B	
L	н	1A = 1B	Z	
н	L	Z	2A = 2B	
Н	Н	Z	Z	

Pin Descriptions

Pin Name	Description	
$\overline{OE}_1, \overline{OE}_2$	Bus Switch Enables	
1A, 2A	Bus A	
1B, 2B	Bus B	
NC	No Connect	

FSTU162211

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) DC Switch Voltage (V_S) (Note 2)	-0.5V to +7.0V -0.5V to +7.0V
DC Input Control	
Pin Voltage (V _{IN}) (Note 3)	-0.5V to +7.0V
DC Input Diode Current (I_{IK}) V_{IN} < 0V	–50 mA
DC Output Current (I _{OUT})	128 mA
DC V _{CC} /GND Current (I _{CC} /I _{GND})	+/- 100 mA
Storage Temperature Range (T_{STG})	–65°C to +150 °C

Recommended Operating Conditions (Note 4)

()	
Power Supply Operating $(V_{CC)}$	4.0V to 5.5V
Input Voltage (V _{IN})	0V to 5.5V
Output Voltage (V _{OUT})	0V to 5.5V
Input Rise and Fall Time (t_r, t_f)	
Switch Control Input	0 ns/V to 5 ns/V
Switch I/O	0 ns/V to DC
Free Air Operating Temperature (T _A)	-40 °C to +85 °C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: V_S is the voltage observed/applied at either the A or B Ports across the switch.

Note 3: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 4: Unused control inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

	Parameter	v	$T_A = -40 \ ^\circ C$ to $+85 \ ^\circ C$				
Symbol		V _{CC} (V)	Min	Typ (Note 5)	Max	Units	Conditions
V _{IK}	Clamp Diode Voltage	4.5			-1.2	V	$I_{IN} = -18 \text{ mA}$
V _{IH}	HIGH Level Input Voltage	4.0-5.5	2.0			V	
V _{IL}	LOW Level Input Voltage	4.0-5.5			0.8	V	
I _I	Input Leakage Current	5.5			±1.0	μA	$0 \le V_{IN} \le 5.5V$
		0			10	μA	$V_{IN} = 5.5V$
I _{OZ}	OFF-STATE Leakage Current	5.5			±1.0	μA	$0 \le A, B \le V_{CC}$
R _{ON}	Switch On Resistance	4.5	20	26	38	Ω	$V_{IN} = 0V, I_{IN} = 64 \text{ mA}$
	(Note 6)	4.5	20	27	40	Ω	$V_{IN} = 0V, I_{IN} = 30 \text{ mA}$
		4.5	20	28	48	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
		4.0	20	30	48	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
I _{CC}	Quiescent Supply Current	5.5			3	μA	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
ΔI_{CC}	Increase in I _{CC} per Input	5.5			2.5	mA	One Input at 3.4V
							Other Inputs at V _{CC} or GND
V _{IKU}	Voltage Undershoot	5.5			-2.0	V	$0.0 \text{ mA} \ge I_{IN} \ge -50 \text{ mA}$
							$\overline{OE}_{1,2} = 5.5v$

Note 5: Typical values are at $V_{CC}=5.0V$ and $T_{A}=+25^{\circ}C$

Note 6: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B) pins.

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AC Electrical Characteristics

Symbol	Parameter		$T_A = -40 \ ^\circ C$ to +85 $^\circ C$, $C_L = 50 pF$, $RU = RD = 500 \Omega$				Units	Conditions	Figure
Gymbol	i arameter	$V_{CC} = 4$.5 – 5.5V	V _{CC} =	= 4.0V	Units	Conditions	Number	
		Min	Max	Min	Max				
t _{PHL} , t _{PLH}	Propagation Delay Bus to Bus (Note 7)		1.25		1.25	ns	V _I = OPEN	Figures 2, 3	
t _{PZH} , t _{PZL}	Output Enable Time	1.5	6.0		6.5	ns	$V_I = 7V$ for t_{PZL} $V_I = OPEN$ for t_{PZH}	Figures 2, 3	
t _{PHZ} , t _{PLZ}	Output Disable Time	1.5	7.0		7.2	ns	$V_I = 7V$ for t_{PLZ} $V_I = OPEN$ for t_{PHZ}	Figures 2, 3	

Note 7: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On Resistance of the switch and the 50pF load capacitance, when driven by an ideal voltage source (zero output impedance).

Capacitance (Note 8)

Symbol	Parameter	Тур	Max	Units	Conditions
C _{IN}	Control Pin Input Capacitance	3		pF	$V_{CC} = 5.0V$
C _{I/O}	Input/Output Capacitance	6		pF	$V_{CC}, \overline{OE} = 5.0V$

Note 8: $T_A = +25^{\circ}C$, f = 1 MHz, Capacitance is characterized but not tested.

Undershoot Characteristic

Symbol	Parameter	Min	Тур	Max	Units	Conditions		
V _{OUTU}	Output Voltage During Undershoot	2.5	V _{OH} – 0.3		V			
Note 9: This	Note 9: This test is intended to characterize the device's protective capabilities by maintaining output signal integrity during an input transient voltage under-							

shoot event.

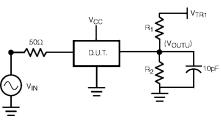
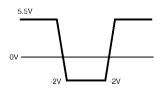


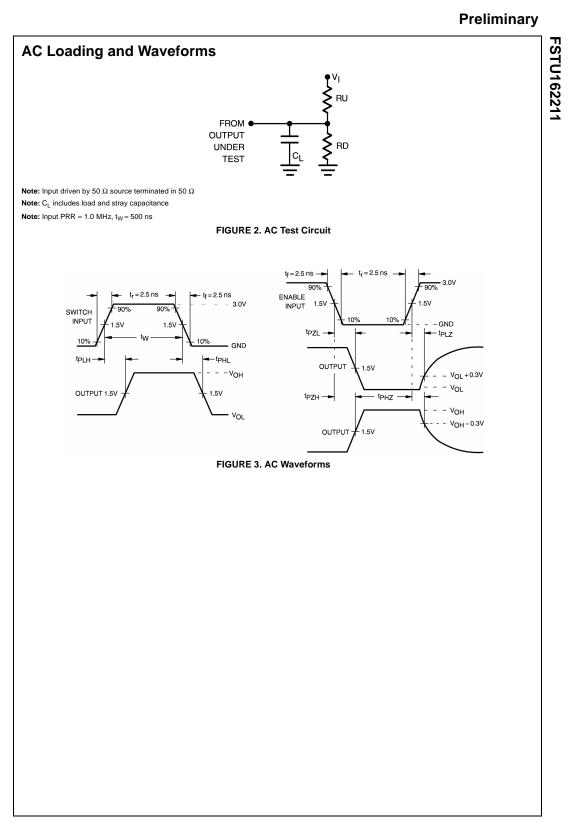
FIGURE 1.

Device Test Conditions

Parameter	Value	Units
V _{IN}	see Waveform	V
$R_1 = R_2$	100K	Ω
V _{TRI}	11.0	V
V _{CC}	5.5	V

Transient Input Voltage (V_{IN}) Waveform





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